

**DESCRIPTION**

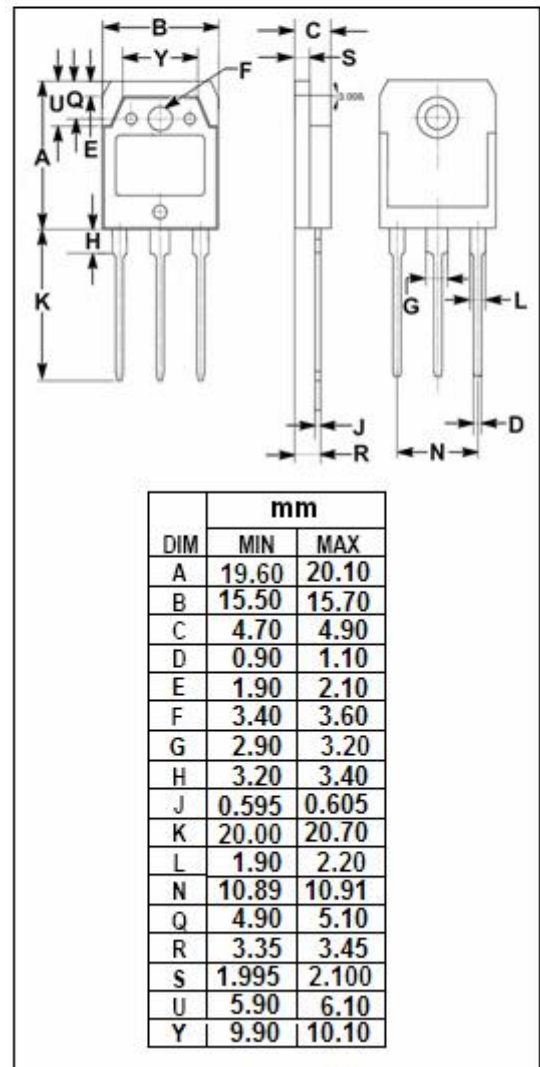
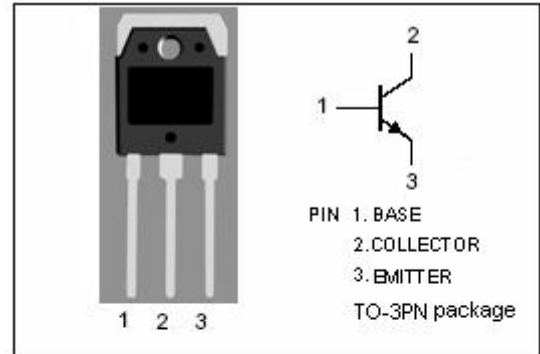
- High Collector-Emitter Breakdown Voltage-  
:  $V_{(BR)CEO} = 400V(\text{Min})$
- High Switching Speed
- Wide Area of Safe Operation

**APPLICATIONS**

- Designed for switching regulator and general purpose applications.

**ABSOLUTE MAXIMUM RATINGS( $T_a=25^\circ\text{C}$ )**

SYMBOL	PARAMETER	VALUE	UNIT
$V_{CBO}$	Collector-Base Voltage	500	V
$V_{CEO}$	Collector-Emitter Voltage	400	V
$V_{EBO}$	Emitter-Base voltage	7	V
$I_C$	Collector Current-Continuous	25	A
$I_{CM}$	Collector Current-Peak $PW \leq 300\mu\text{s}$ , duty cycle $\leq 10\%$	40	A
$I_B$	Base Current-Continuous	8	A
$P_C$	Collector Power Dissipation @ $T_c=25^\circ\text{C}$	160	W
	Collector Power Dissipation @ $T_a=25^\circ\text{C}$	2.5	
$T_J$	Junction Temperature	150	$^\circ\text{C}$
$T_{stg}$	Storage Temperature Range	-55~150	$^\circ\text{C}$



**ELECTRICAL CHARACTERISTICS**

T<sub>c</sub>=25°C unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP.	MAX	UNIT
V <sub>(BR)CBO</sub>	Collector-Base Breakdown Voltage	I <sub>C</sub> = 1mA; I <sub>E</sub> = 0	500			V
V <sub>(BR)CEO</sub>	Collector-Emitter Breakdown Voltage	I <sub>C</sub> = 10mA; R <sub>BE</sub> = ∞	400			V
V <sub>(BR)EBO</sub>	Emitter-Base Breakdown Voltage	I <sub>E</sub> = 1mA; I <sub>C</sub> = 0	7			V
V <sub>CE(sat)</sub>	Collector-Emitter Saturation Voltage	I <sub>C</sub> = 16A; I <sub>B</sub> = 3.2A			0.8	V
V <sub>BE(sat)</sub>	Base-Emitter Saturation Voltage	I <sub>C</sub> = 16A; I <sub>B</sub> = 3.2A			1.5	V
I <sub>CBO</sub>	Collector Cutoff Current	V <sub>CB</sub> = 400V ; I <sub>E</sub> = 0			10	μ A
I <sub>EBO</sub>	Emitter Cutoff Current	V <sub>EB</sub> = 5V; I <sub>C</sub> = 0			10	μ A
h <sub>FE-1</sub>	DC Current Gain	I <sub>C</sub> = 3.2A ; V <sub>CE</sub> = 5V	15		50	
h <sub>FE-2</sub>	DC Current Gain	I <sub>C</sub> = 16A ; V <sub>CE</sub> = 5V	10			
h <sub>FE-3</sub>	DC Current Gain	I <sub>C</sub> = 10mA ; V <sub>CE</sub> = 5V	10			
f <sub>T</sub>	Current-Gain—Bandwidth Product	I <sub>C</sub> = 3.2A ; V <sub>CE</sub> = 10V		20		MHz
C <sub>OB</sub>	Output Capacitance	I <sub>E</sub> = 0; V <sub>CB</sub> = 10V; f <sub>test</sub> = 1.0MHz		300		pF

Switching Times

t <sub>on</sub>	Turn-on Time	I <sub>C</sub> = 20A, I <sub>B1</sub> = 4A; I <sub>B2</sub> = -8A R <sub>L</sub> = 10 Ω ; V <sub>CC</sub> = 200V			0.5	μ s
t <sub>stg</sub>	Storage Time				2.5	μ s
t <sub>f</sub>	Fall Time				0.3	μ s

◆ **h<sub>FE-1</sub> Classifications**

L	M	N
15-30	20-40	30-50